
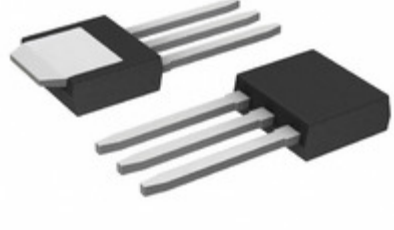
	<h2>NTD80N02-1G</h2>
	<p><b>Hersteller-Teilenummer:</b> NTD80N02-1G</p> <p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 24V 80A IPAK</p> <p><b>Datenblätter:</b>  <a href="#">NTD80N02-1G.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 11029 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	NTD80N02-1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 24V 80A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	11029 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	75W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	24V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	80A (Tc)
Rds On (Max) @ Id, Vgs	5.8 mOhm @ 80A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	42nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	2600pF @ 20V
Verpackung	Tube

NTD80N02-1G ist neu im Original, Suche NTD80N02-1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD80N02-1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD80N02-1G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTD80N02-001</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 80A IPAK</p>	 <p><b>NTD80N02T4G NTD80N02</b> ON/ ON/ SOT-252</p>	 <p><b>NTD80N02G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 80A DPAK</p>	 <p><b>NTD78N03T4G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 11.4A DPAK</p>
 <p><b>NTD80N02T4</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 80A DPAK</p>	 <p><b>NTD80N03T4G</b> ON NTD80N03T4G ON</p>	 <p><b>NTD80N02</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 80A DPAK</p>	 <p><b>NTD80N02T4G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 80A DPAK</p>

### heiße Teile

Mehr

NTD6600NT4	NTD6600NT4G	NTD70N03	NTD70N03R	NTD70N03R-001
NTD70N03R-1	NTD70N03R-1G	NTD70N03RG	NTD70N03RT4	NTD70N03RT4G
NTD70N03TR4	NTD78N03	NTD78N03-001	NTD78N03-035	NTD78N03-1
NTD78N03-1G	NTD78N03-35G	NTD78N03R-001	NTD78N03R-1G	NTD78N03RT4G
NTD78N03T4	NTD78N03T4G	NTD80N02	NTD80N02-001	NTD80N02-1
NTD80N02G	NTD80N02T4	NTD80N02T4G	NTD85N02-1G	NTD85N02R
NTD85N02R-001	NTD85N02R-1	NTD85N02R-1G	NTD85N02R14	NTD85N02RG
NTD85N02RT4G	NTD85N02T4G	NTD95N02-001	NTD95N02-1G	NTD95N02R
NTD95N02R-1G	NTD95N02RG	NTD95N02RT4G	NTDV18N06LT4G	NTDV20N06LT4G
NTDV20N06T4G	NTDV20P06LT4G	NTDV20P06LT4G	NTDV2955PT4G	NTDV3055L104T4G

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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